



DMN2028UFDF

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
	25mΩ @ V _{GS} = 4.5V	7.9A
2014	29mΩ @ V _{GS} = 2.5V	7.2A
20V	39mΩ @ V _{GS} = 1.8V	6.1A
	95mΩ @ V _{GS} = 1.5V	4.0A

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Battery Management Application
- Power Management Functions
- DC-DC Converters

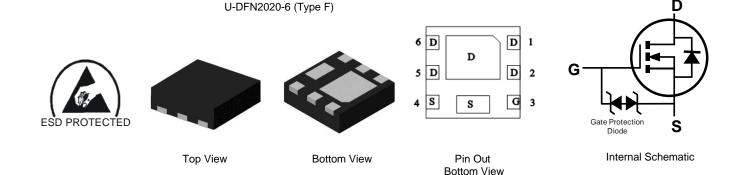
20V N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low Gate Threshold Voltage
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0065 grams (Approximate)



Ordering Information (Note 4)

Part Number	Reel Size (inches)	Quantity per Reel
DMN2028UFDF-7	7	3,000
DMN2028UFDF-13	13	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

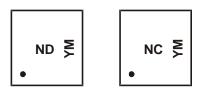
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1

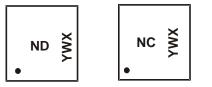


ND or NC = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2015		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	С		Н		J	K	L	М	Ν	0	Р	R
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2



ND or NC = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020)

W = Week (ex: a = week 27; z represents week 52 and 53)

X = Internal Code (ex: U = Monday)

Date Code Key

Year	2015		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	5		0	1	2	3	4	5	6	7	8	9
Week	1-26			27-52				53				
Code		A	λ-Ζ		a-z				Z			
Internal Code	Su	n	Mor	า	Tue		Wed	Thu	1	Fri		Sat
Code	Т		U		V		W	Х		Y		Z



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	Vdss	20	V		
Gate-Source Voltage			V _{GSS}	±8	V
Continuous Drain Current (Note C) \/ 4.5\/	Steady State	T _A = +25°C T _A = +70°C	lD	7.9 6.3	А
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$	T _A = +25°C T _A = +70°C	lD	9.4 7.5	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%))		IDM	40	А
Continuous Source-Drain Diode Current	T _A = +25°C	ls	2	А	
Avalanche Current (Note 7) L = 0.1mH	las	12	А		
Avalanche Energy (Note 7) L = 0.1mH			E _{AS}	8	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit	
Total Davies Disaination (Nata 5)	T _A = +25°C		0.66	14/	
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.42	W	
Thermal Resistance Junction to Ambient (Note 5)	Steady state	Davi	186	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t<5s	Reja	135		
Total Power Dissipation (Note 6)	T _A = +25°C	Pn	2.03	W	
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	PD	1.31		
Thermal Resistance Junction to Ambient (Note 6)	Steady state	Devi	64	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<5s	R _{0JA}	43		
Thermal Resistance, Junction to Case (Note 6)	Steady state	Rejc	18		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

			•			-
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)			-		-	1
Drain-Source Breakdown Voltage	BV _{DSS}	20	_	—	V	$V_{GS} = 0V, I_{D} = 250 \mu A$
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	—	_	1	μA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	—	_	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	0.5	_	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
			15	25		$V_{GS} = 4.5V, I_{D} = 4A$
Static Drain-Source On-Resistance	D		18	29	mΩ	Vgs = 2.5V, ID = 4A
Static Drain-Source OI-Resistance	R _{DS(ON)}	_	24	39	111112	$V_{GS} = 1.8V, I_D = 4A$
			35	95		Vgs = 1.5V, ID = 4A
Forward Transfer Admittance	Yfs	—	18	_	S	V _{DS} = 5V, I _D = 12A
Diode Forward Voltage	Vsd	—	0.7	1.0	V	$V_{GS} = 0V$, $I_S = 5A$
DYNAMIC CHARACTERISTICS (Note 9)						·
Input Capacitance	Ciss	—	907	—		
Output Capacitance	Coss	—	98	—	pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	38	—		
Gate Resistance	Rg	—	194	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	—	9.8	—		
Total Gate Charge (V _{GS} = 8V)	Qg	—	18	—	nC	
Gate-Source Charge	Qgs	—	1.5	—	nc	$V_{DS} = 10V, I_{D} = 6.5A$
Gate-Drain Charge	Q _{gd}	_	1.8	—		
Turn-On Delay Time	t _{D(ON)}	—	56	—		
Turn-On Rise Time	tR	_	87	—		$V_{DS} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t _{D(OFF)}	_	632	—	ns	$R_G = 6\Omega$, $R_L = 10\Omega$, $I_D = 1A$
Turn-Off Fall Time	tF	—	239	—	1	
Reverse Recovery Time	t _{RR}	—	143	—	ns	IF = 4A, di/dt = 100A/µs
Reverse Recovery Charge	Q _{RR}		136	—	nC	$I_F = 4A$, di/dt = 100A/µs

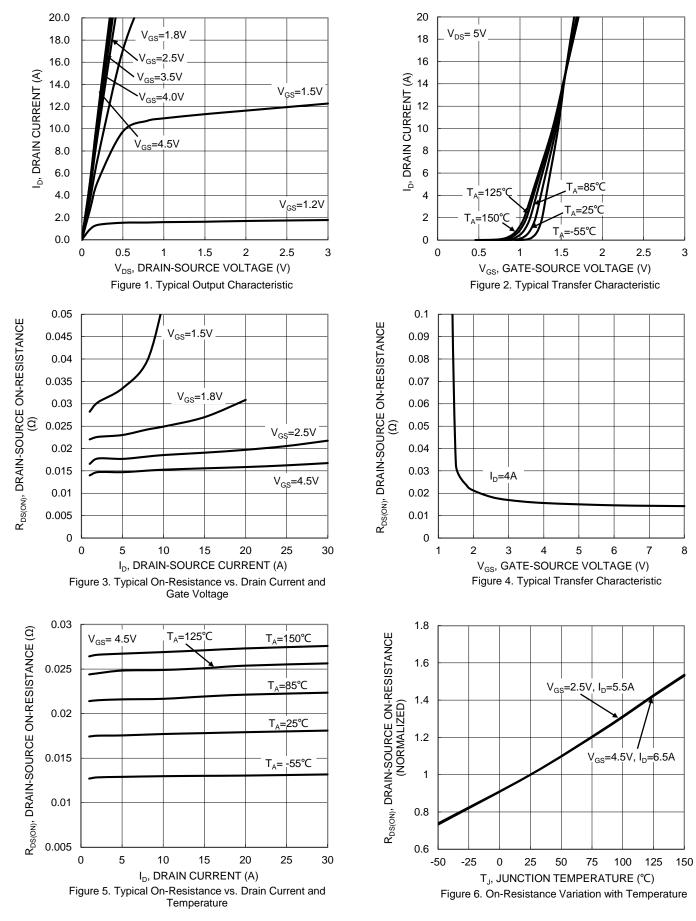
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

5. Device mounted on FR-4 substrate PC board, 202 copper, with 1inch square commence parts of the substrate PC board, 202 copper, with 1inch square copper plate. 7. IAs and EAs ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}$ C. 8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.



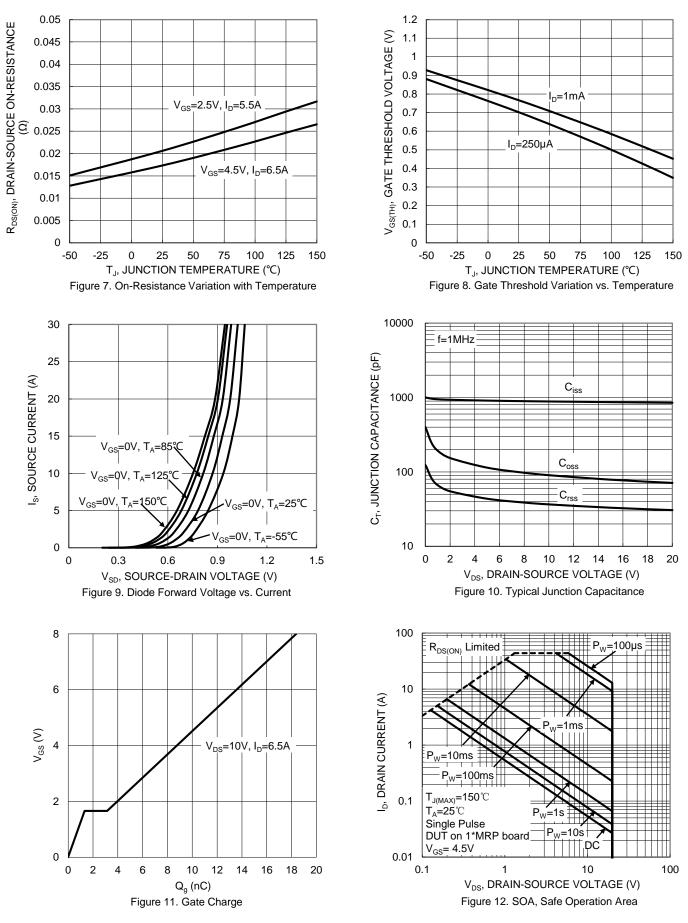
DMN2028UFDF



DMN2028UFDF Datasheet number: DS37937 Rev. 3 - 2

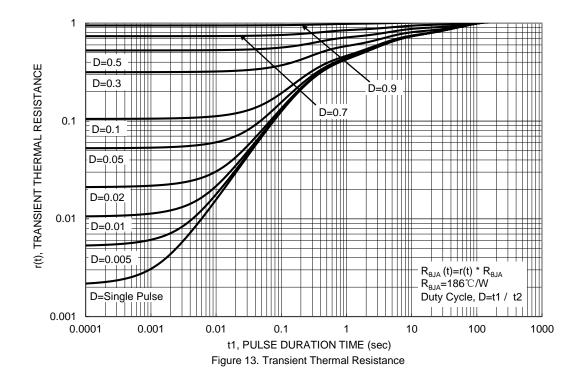


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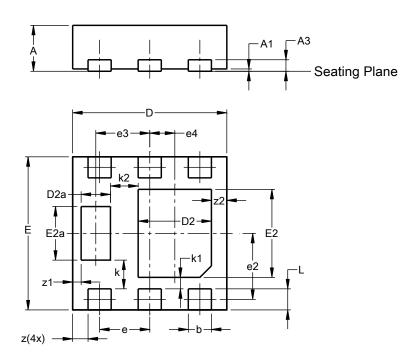






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



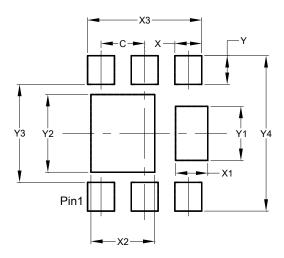
U-DFN2020-6 (Type F)

U-DFN2020-6								
	(Тур	be F)						
Dim	Min	Min Max Typ						
Α	0.57	0.63	0.60					
A1	0.00	0.05	0.03					
A3	-	-	0.15					
b	0.25	0.35	0.30					
D	1.95	2.05	2.00					
D2	0.85	1.05	0.95					
D2a	0.33	0.43	0.38					
Ш	1.95	2.05	2.00					
E2	1.05	1.25	1.15					
E2a	0.65	0.75	0.70					
e		0.65 BS	С					
e2	C).863 BS	SC					
e3		0.70 BS	С					
e4	C).325 BS	SC					
k		0.37 BS	С					
k1	0.15 BSC							
k2		0.36 BS	С					
L	0.225	0.325	0.275					
z		0.20 BS						
z1	C).110 BS	SC					
z2		0.20 BS	С					
All D	imens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)



Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



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